HARRIS SEMICONDUCTOR

CD74FCT646

January 1997

NOT RECOMMENDED FOR NEW DESIGNS
Use CMOS Technology

BiCMOS FCT Interface Logic, Octal Bus Transceiver/Register, Three-State

Features

- **Buffered Inputs**
- **Typical Propagation Delay: 6.8ns at V_{CC} = 5V, T_A = 25°C, C_L = 50pF**
- **Noninverting**
- **SCR Latchup Resistant BiCMOS Process and Circuit Design**
- **Speed of Bipolar FAST™/AS/S**
- **64mA Output Sink Current**
- **Output Voltage Swing Limited to 3.7V at V_{CC} = 5V**
- **Controlled Output Edge Rates**
- **Input/Output Isolation to V_{CC}**
- **BiCMOS Technology with Low Quiescent Power**

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74FCT646EN	0 to 70	24 Ld PDIP	E24.3
CD74FCT646M	0 to 70	24 Ld SOIC	M24.3
CD74FCT646SM	0 to 70	24 Ld SSOP	M24.209

NOTE: When ordering the suffix M and SM packages, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

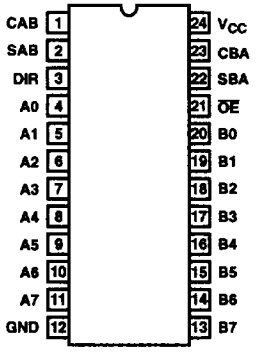
Description

The CD74FCT646 three-state octal bus transceiver/register uses a small geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output HIGH level to two diode drops below V_{CC}. This resultant lowering of output swing (0V to 3.7V) reduces power bus ringing (a source of EMI) and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 milliamperes.

This device is a bus transceiver with D-Type flip-flops which act as internal storage registers on the LOW to HIGH transition of either CAB or CBA clock inputs. Output Enable ($\overline{OE}$) and Direction (DIR) inputs control the transceiver functions. Data present at the high impedance output can be stored in either register or both but only one of the two buses can be enabled as outputs at any one time. The Select controls (SAB and SBA) can multiplex stored and transparent (real time) data. The Direction control determines which data bus will receive data when the Output Enable ($\overline{OE}$) is LOW. In the high impedance mode (Output Enable HIGH), A data can be stored in one register and B data can be stored in the other register. The clocks are not gated with the Direction (DIR) and Output Enable ($\overline{OE}$) terminals; data at the A or B terminals can be clocked into the storage flip-flops at any time.

Pinout

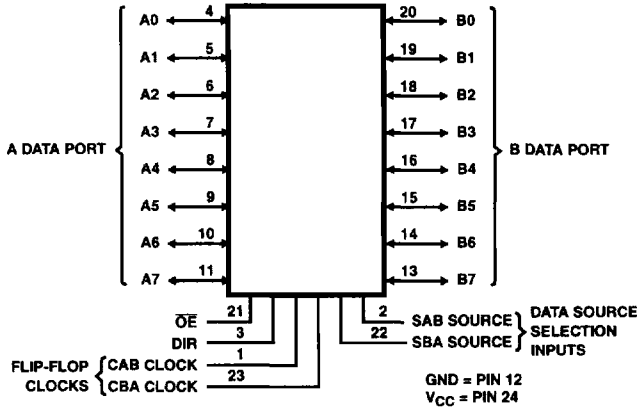
CD74FCT646
(PDIP, SOIC, SSOP)
TOP VIEW



8 BiCMOS FCT PRODUCTS

File Number **2393.2**

Functional Diagram



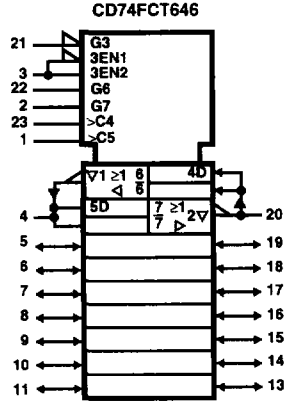
TRUTH TABLE (Note 1)

INPUTS						DATA I/O (Note 2)		OPERATION OR FUNCTION
OE	DIR	CAB	CBA	SAB	SBA	A0 THRU A7	B0 THRU B7	CD74FCT646
X X	X X	↑ X	X ↑	X X	X X	Input Not Specified	Not Specified Input	Store A, B Unspecified Store B, A Unspecified
H H	X X	↑ H or L	↑ H or L	X X	X X	Input	Input	Store A and B Data Isolation, Hold Storage
L L	L L	X X	X H or L	X X	L H	Output	Input	Real Time B Data to A Bus Stored B Data to A Bus
L L	H H	X H or L	X X	L H	X X	Input	Output	Real Time A Data to B Bus Stored A Data to B Bus

NOTES:

1. H= HIGH Voltage Level
   L = LOW Voltage Level
   ↑ = Transition from Low to High
   X = Immaterial
2. The data output functions may be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low to high transition of the clock inputs. To prevent excess currents in the high Z modes, all I/O terminals should be terminated with 10kΩ resistors.

IEC Logic Symbol



Absolute Maximum Ratings

DC Supply Voltage (V_{CC}) . . . . . -0.5V to 6V
DC Diode Current, I_{IK} (For V_I < -0.5V) . . . . . -20mA
DC Output Diode Current, I_{OK} (for V_O < -0.5V) . . . . . -50mA
DC Output Sink Current per Output Pin, IO 70mA
DC Output Source Current per Output Pin, IO . . . . . -30mA
DC V_{CC} Current (I_{CC}) 140mA
DC Ground Current (I_{GND}) 528mA

Thermal Information

Thermal Resistance (Typical, Note 3) θ_{JA} (°C/W)
PDIP Package 75
SOIC Package 75
SSOP Package 125
Maximum Junction Temperature . . . . . 150°C
Maximum Storage Temperature Range . . . . . -65°C to 150°C
Maximum Lead Temperature (Soldering 10s) . . . . . 300°C
(SOIC and SSOP-Lead Tips Only)

Operating Conditions

Operating Temperature Range, T_A . . . . . 0°C to 70°C
Supply Voltage Range, V_{CC} . . . . . 4.75V to 5.25V
DC Input Voltage, V_I . . . . . 0 to V_{CC}
DC Output Voltage, V_O . . . . . 0 to ≤ V_{CC}
Input Rise and Fall Slew Rate, dt/dv . . . . . 0 to 10ns/V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications Commercial Temperature Range 0°C to 70°C, V_{CC} Max = 5.25V, V_{CC} Min = 4.75V (Note 6)

PARAMETER	SYMBOL	TEST CONDITIONS			AMBIENT TEMPERATURE (T_A)				UNITS
					25°C		0°C TO 70°C		
		V_I (V)	I_O (mA)	V_{CC} (V)	MIN	MAX	MIN	MAX	
High Level Input Voltage	V_{IH}			4.75 to 5.25	2	-	2	-	V
Low Level Input Voltage	V_{IL}			4.75 to 5.25	-	0.8	-	0.8	V
High Level Output Voltage	V_{OH}	V_{IH} or V_{IL}	-15	Min	2.4	-	2.4	-	V
Low Level Output Voltage	V_{OL}	V_{IH} or V_{IL}	64	Min	-	0.55	-	0.55	V
High Level Input Current	I_{IH}	V_{CC}		Max	-	0.1	-	1	µA
Low Level Input Current	I_{IL}	GND		Max	-	-0.1	-	-1	µA
Three-State Leakage Current	I_{OZH}	V_{CC}		Max	-	0.5	-	10	µA
	I_{OZL}	GND		Max	-	-0.5	-	-10	µA
Input Clamp Voltage	V_{IK}	V_{CC} or GND	-18	Min	-	-1.2	-	-1.2	V
Short Circuit Output Current (Note 4)	I_{OS}	V_O = 0 V_{CC} or GND		Max	-60	-	-60	-	mA
Quiescent Supply Current, MSI	I_{CC}	V_{CC} or GND	0	Max	-	8	-	80	µA
Additional Quiescent Supply Current per Input Pin TTL Inputs High, 1 Unit Load	ΔI_{CC}	3.4V (Note 5)		Max	-	1.6	-	1.6	mA

NOTES:

4. Not more than one output should be shorted at one time. Test duration should not exceed 100ms.
5. Inputs that are not measured are at V_{CC} or GND.
6. FCT Input Loading: All inputs are 1 unit load. Unit load is ΔI_{CC} limit specified in Electrical Specifications table, e.g., 1.6mA Max. at 70°C.

Switching Specifications Over Operating Range FCT Series t_r, t_f = 2.5ns, C_L = 50pF, R_L (Figure 1) (Note 7)

PARAMETER	SYMBOL	V_{CC} (V)	25°C	0°C TO 70°C		UNITS
			TYP	MIN	MAX	
Propagation Delays		(Note 8)				
Store An → Bn, Store Bn → An, An → Bn, Bn → An	t_{PLH}, t_{PHL}	5	6.8	2	9	ns
Select to Data	t_{PLH}, t_{PHL}	5	8.3	2	11	ns
Output Enable to Output	t_{PZL}, t_{PZH}	5	10.5	2	14	ns
Output Disable to Output	t_{PLZ}, t_{PHZ}	5	6.8	2	9	ns
Power Dissipation Capacitance	C_{PD} (Note 8)	-	-	-	-	pF
Minimum (Valley) V_{OHV} During Switching of Other Outputs (Output Under Test Not Switching)	V_{OHV}	5	0.5	-	-	V
Maximum (Peak) V_{OLP} During Switching of Other Outputs (Output Under Test Not Switching)	V_{OLP}	5	1	-	-	V
Input Capacitance	C_I	-	-	-	10	pF
Input/Output Capacitance	$C_{I/O}$	-	-	-	15	pF

NOTES:

7. 5V: Minimum is at 5.25V for 0°C to 70°C, Maximum is at 4.75V for 0°C to 70°C, Typical is at 5V.
8. C_{PD}, measured per flip-flop, is used to determine the dynamic power consumption.
   P_D (per package) = $V_{CC} I_{CC} + \Sigma(V_{CC}^2 f_I C_{PD} + V_O^2 f_O C_L + V_{CC} \Delta I_{CC} D)$ where:
   V_{CC} = supply voltage
   ΔI_{CC} = flow through current x unit load
   C_L = output load capacitance
   D = duty cycle of input high
   f_O = output frequency
   f_I = input frequency

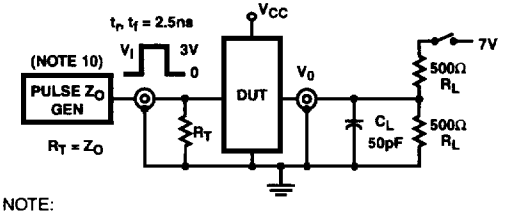
Prerequisite For Switching

PARAMETER	SYMBOL	V_{CC} (V)	25°C	0°C TO 70°C		UNITS
			TYP	MIN	MAX	
Maximum Frequency	f_{MAX}	5 (Note 9)	-	85	-	ns
Data to Clock Setup Time	t_{SU}	5	-	4	-	ns
Data to Clock Hold Time	t_H	5	-	2	-	ns
Clock Pulse Width	t_W	5	-	6	-	ns

NOTE:

9. 5V: Minimum is at 4.75V for 0°C to 70°C, Typical is at 5V.

Test Circuits and Waveforms



NOTE:

10. Pulse Generator for All Pulses: Rate ≤ 1.0MHz; Z_{OUT} ≤ 50Ω; t_f, t_r ≤ 2.5ns.

FIGURE 1. TEST CIRCUIT

SWITCH POSITION

TEST	SWITCH
t_{PLZ}, t_{PZL}, Open Drain	Closed
t_{PHZ}, t_{PZH}, t_{PLH}, t_{PHL}	Open

DEFINITIONS:

C_L = Load capacitance, includes jig and probe capacitance.

R_T = Termination resistance, should be equal to Z_{OUT} of the Pulse Generator.

V_{IN} = 0V to 3V.

Input: $t_r = t_f$ = 2.5ns (10% to 90%), unless otherwise specified

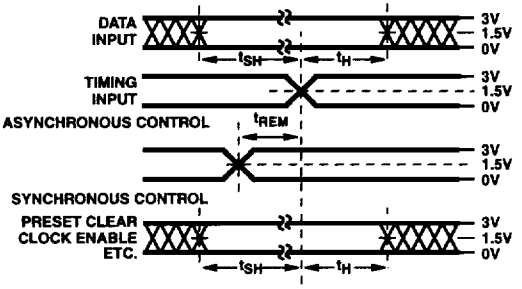


FIGURE 2. SETUP, HOLD, AND RELEASE TIMING

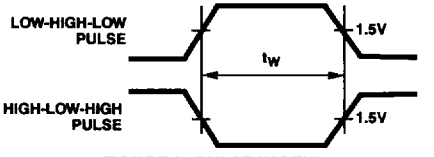


FIGURE 3. PULSE WIDTH

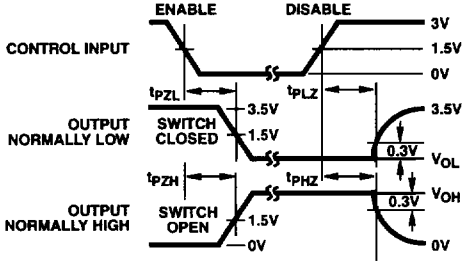


FIGURE 4. ENABLE AND DISABLE TIMING

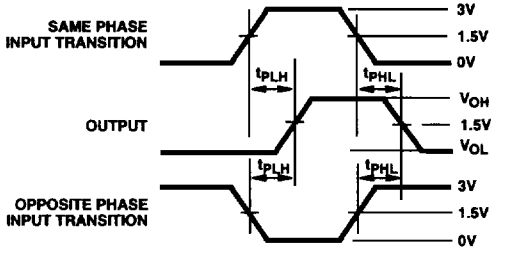
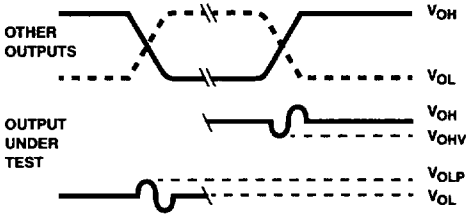


FIGURE 5. PROPAGATION DELAY



NOTES:

11. V_{OLP} is measured with respect to a ground reference near the output under test. V_{OHV} is measured with respect to V_{OH}.
12. Input pulses have the following characteristics: P_{RR} ≤ 1MHz, t_r = 2.5ns, t_f = 2.5ns, skew 1ns.
13. R.F. fixture with 700MHz design rules required. IC should be soldered into test board and bypassed with 0.1µF capacitor. Scope and probes require 700MHz bandwidth.

FIGURE 6. SIMULTANEOUS SWITCHING TRANSIENT WAVEFORMS